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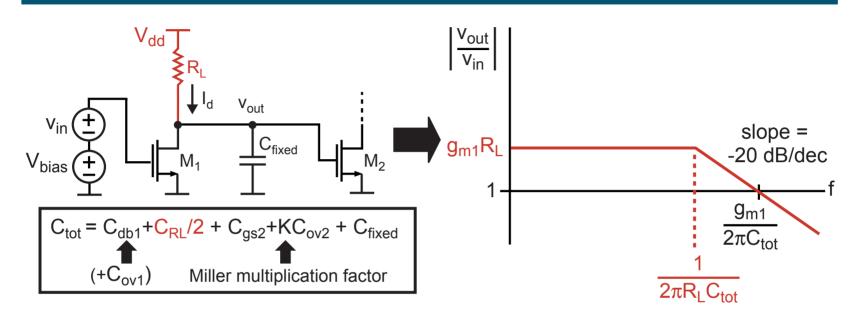
#### **6.976**

High Speed Communication Circuits and Systems Lecture 6 Enhancement Techniques for Broadband Amplifiers, Narrowband Amplifiers

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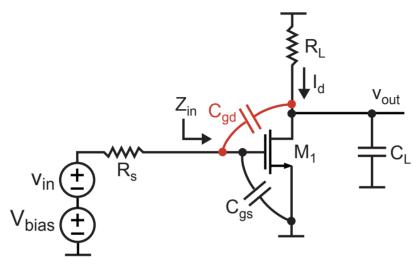
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## Resistor Loaded Amplifier (Unsilicided Poly)



- We decided this was the fastest non-enhanced amplifier
  - Can we go faster? (i.e., can we enhance its bandwidth?)
- We will look at the following
  - Reduction of Miller effect on C<sub>gd</sub>
  - Shunt, series, and zero peaking
  - Distributed amplification

# Miller Effect on C<sub>gd</sub> Is Significant

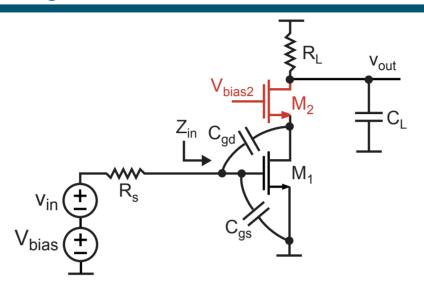


- C<sub>gd</sub> is quite significant compared to C<sub>gs</sub>
   In 0.18µ CMOS, C<sub>gd</sub> is about 45% the value of C<sub>gs</sub>
- Input capacitance calculation

$$Z_{in} \approx \frac{1}{s(C_{gs} + C_{gd}(1 - A_v))} = \frac{1}{sC_{gs}(1 + C_{gd}/C_{gs}(1 + g_m R_L))}$$
  
- For 0.18µ CMOS, gain of 3, input cap is almost tripled  
over C<sub>gs</sub>! 
$$Z_{in} \approx \frac{1}{sC_{gs}(1 + 0.45(4))} = \frac{1}{sC_{gs}2.8}$$

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## **Reduction of C<sub>qd</sub> Impact Using a Cascode Device**



The cascode device lowers the gain seen by C<sub>gd</sub> of M<sub>1</sub>

$$A_v \to g_{m1} \frac{1}{g_{m2}} \approx 1 \quad \Rightarrow \quad Z_{in} \approx \frac{1}{sC_{gs}(1 + C_{gd}/C_{gs}(2))}$$

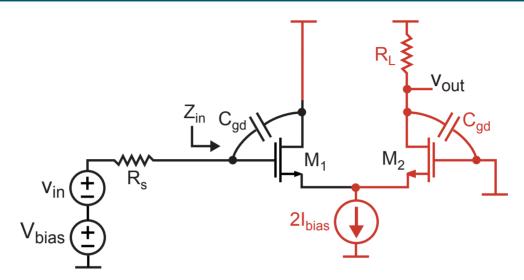
For 0.18m CMOS and gain of 3, impact of C<sub>gd</sub> is reduced by 30%:

$$Z_{in} \approx \frac{1}{sC_{gs}1.9}$$

Issue: cascoding lowers achievable voltage swing

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### **Source-Coupled Amplifier**



Remove impact of Miller effect by sending signal through source node rather than drain node

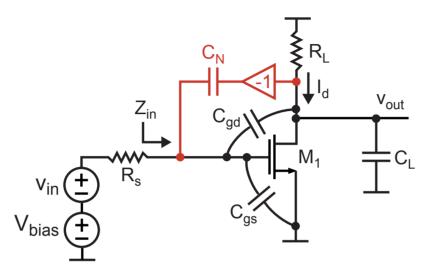
C<sub>gd</sub> not Miller multiplied AND impact of C<sub>gs</sub> cut in half!

$$Z_{in} \approx \frac{1}{s(C_{gs}/2 + C_{gd})} \Rightarrow Z_{in} \approx \frac{1}{sC_{gs}0.95}$$
(0.18 $\mu$  CMOS)

- The bad news
  - Signal has to go through source node (C<sub>sb</sub> significant)
  - Power consumption doubled

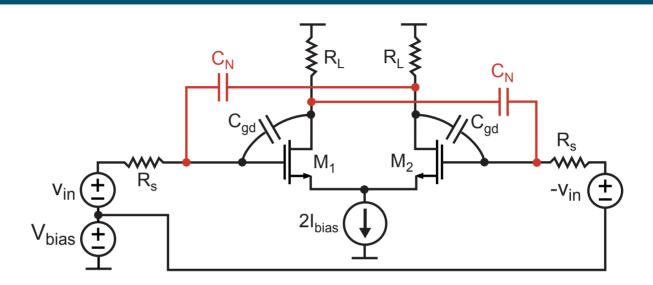
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## Neutralization



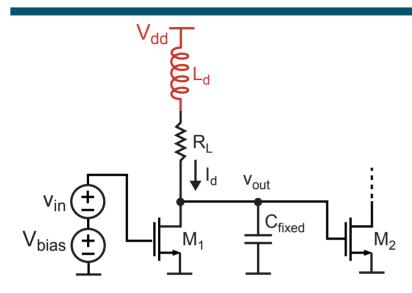
- Consider canceling the effect of C<sub>ad</sub>
  - Choose  $C_N = C_{gd}$
  - Charging of  $C_{gd}$  now provided by  $C_{N}$
- Benefit: Impact of  $C_{gd}$  removed  $\Rightarrow Z_{in} \approx \frac{1}{sC_{as}}$
- **Issues**:
  - How do we create the inverting amplifier?
  - What happens if C<sub>N</sub> is not precisely matched to C<sub>ad</sub>?

## **Practical Implementation of Neutralization**



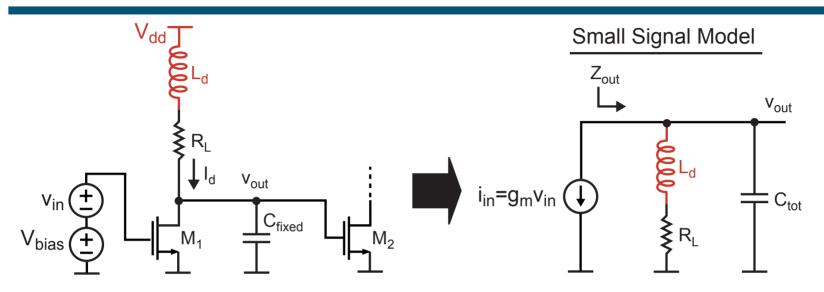
- Leverage differential signaling to create an inverted signal
- Only issue left is matching C<sub>N</sub> to C<sub>gd</sub>
  - Often use lateral metal caps for C<sub>N</sub> (or CMOS transistor)
  - If C<sub>N</sub> too low, residual influence of C<sub>gd</sub>
  - If C<sub>N</sub> too high, input impedance has inductive component
    - Causes peaking in frequency response
    - Often evaluate acceptable level of peaking using eye diagrams

### **Shunt-peaked Amplifier**



- Use inductor in load to extend bandwidth
  - Often implemented as a spiral inductor
- We can view impact of inductor in both time and frequency
  - In frequency: peaking of frequency response
  - In time: delay of changing current in R<sub>L</sub>
- Issue can we extend bandwidth without significant peaking?

#### Shunt-peaked Amplifier - Analysis



Expression for gain

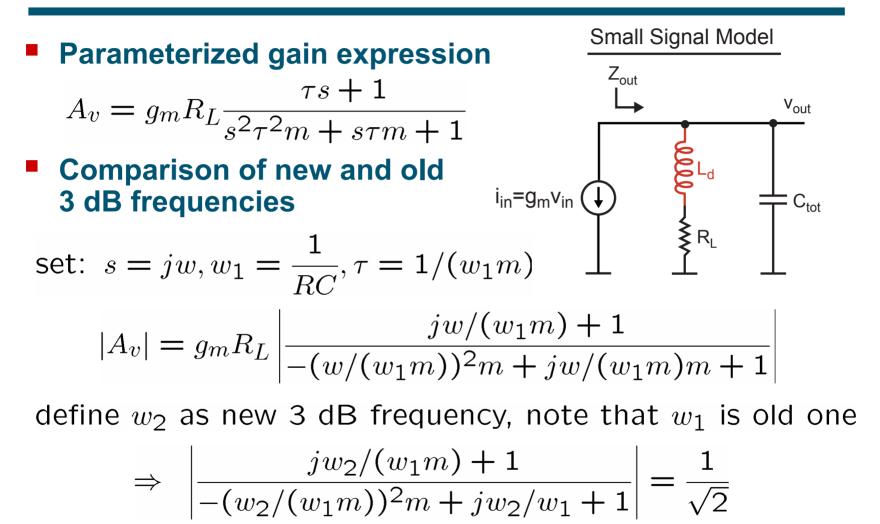
$$A_{v} = g_{m}Z_{out} = g_{m}[(sL_{d} + R_{L})||1/(sC_{tot})]$$

$$= g_{m}R_{L}\frac{s(L_{d}/R_{L}) + 1}{s^{2}L_{d}C_{tot} + sR_{L}C_{tot} + 1}$$

$$m = \frac{R_{L}C_{tot}}{\tau}, \text{ where } \tau = \frac{L_{d}}{R_{L}}$$

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## The Impact of Choosing Different Values of m – Part 1



Want to solve for w<sub>2</sub>/w<sub>1</sub>

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The Impact of Choosing Different Values of m – Part 2

From previous slide, we have

$$\frac{jw_2/(w_1m)+1}{-(w_2/(w_1m))^2m+jw_2/w_1+1} = \frac{1}{\sqrt{2}}$$

After much algebra

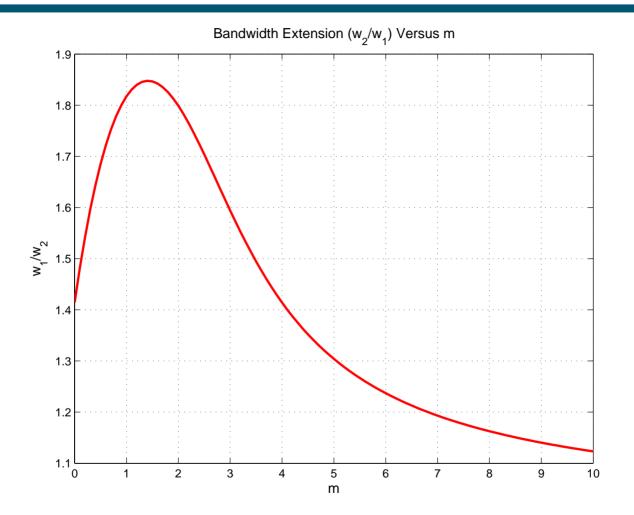
$$\frac{w_2}{w_1} = \sqrt{\left(-\frac{m^2}{2} + m + 1\right) + \sqrt{\left(-\left(\frac{m^2}{2} + m + 1\right)^2 + m^2\right)}}$$

We see that m directly sets the amount of bandwidth extension!

Once m is chosen, inductor value is

$$L_d = \frac{R_L^2 C_{tot}}{m}$$

## Plot of Bandwidth Extension Versus m

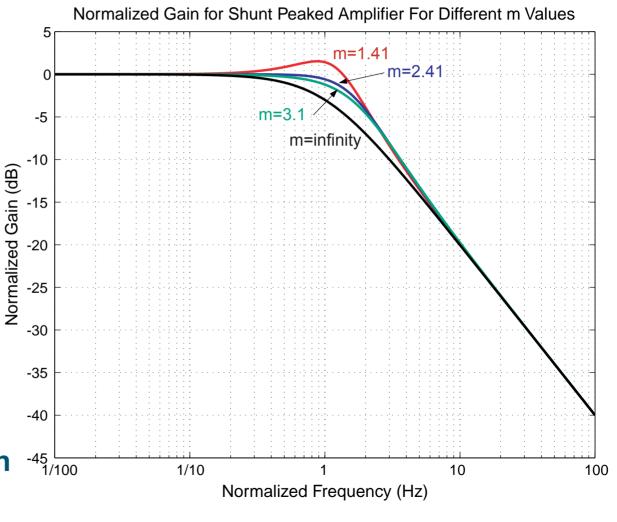


• Highest extension:  $w_2/w_1 = 1.85$  at m  $\approx 1.41$ 

However, peaking occurs!

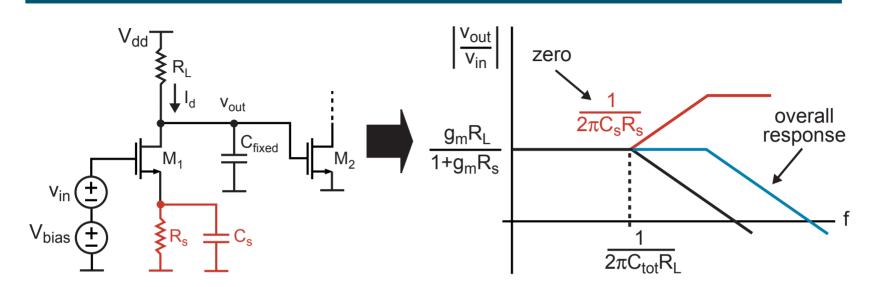
## Plot of Transfer Function Versus m

- Maximum bandwidth: m = 1.41 (extension = 1.85)
- Maximally flat response: m = 2.41 (extension = 1.72)
- Best phase response: m = 3.1 (extension = 1.6)
- No peaking: m = infinity
- Eye diagrams often used to evaluate best m



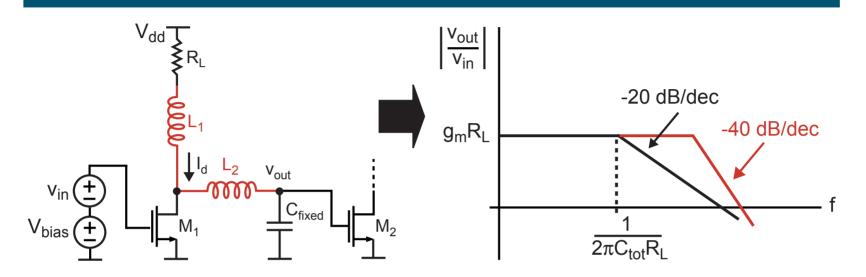
Add eye diagrams

### Zero-peaked Common Source Amplifier



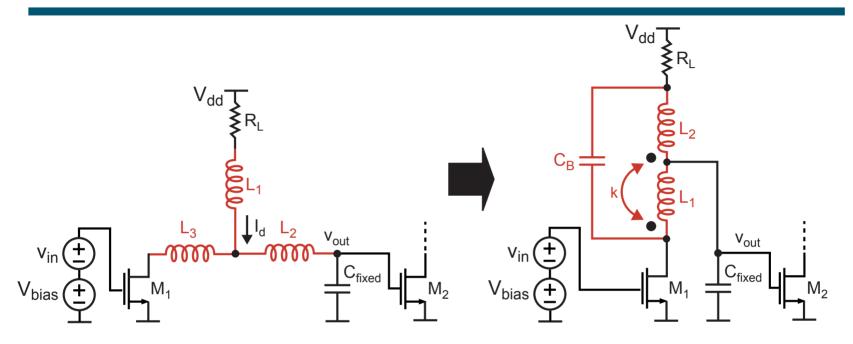
- Inductors are expensive with respect to die area
- We can instead achieve bandwidth extension with capacitor
  - Idea: degenerate gain at low frequencies, remove degeneration at higher frequencies (i.e., create a zero)
- Issues:
  - Must increase R<sub>L</sub> to keep same gain (lowers pole)
  - Lowers achievable gate voltage bias (lowers device f<sub>t</sub>)

#### **Back to Inductors – Shunt and Series Peaking**



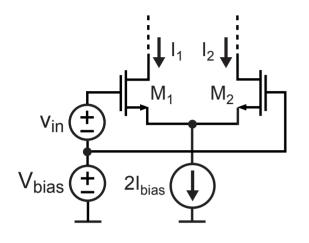
- Combine shunt peaking with a series inductor
  - Bandwidth extension by converting to a second order filter response
    - Can be designed for proper peaking
- Increases delay of amplifier

## **T-Coil Bandwidth Enhancement**



- Uses coupled inductors to realize T inductor network
  - Works best if capacitance at drain of M<sub>1</sub> is much less than the capacitance being driven at the output load
- See Chap. 8 of Tom Lee's book (pp 187-191) for analysis
- See S. Galal, B. Ravazi, "10 Gb/s Limiting Amplifier and Laser/Modulator Driver in 0.18u CMOS", ISSCC 2003, pp 188-189 and "Broadband ESD Protection …", pp. 182-183 M.H. Perrott

## **Bandwidth Enhancement With f<sub>t</sub> Doublers**



A MOS transistor has f<sub>t</sub> calculated as

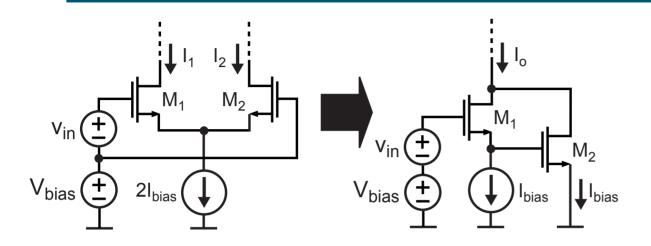
$$2\pi f_t = \frac{g_m}{C_{gs} + C_{gd}} \approx \frac{g_m}{C_{gs}}$$

- f<sub>t</sub> doubler amplifiers attempt to increase the ratio of transconductance to capacitance
- We can make the argument that differential amplifiers are f<sub>t</sub> doublers
  - Capacitance seen by  $V_{in}$  for single-ended input:  $C_{qs}/2$
  - Difference in current:

$$i_2 - i_1 = \frac{v_{in}}{2}g_m - \left(-\frac{v_{in}}{2}\right)g_m = v_{in}g_m$$

• Transconductance to Cap ratio is doubled:  $\frac{2g_m}{C_{as}}$ 

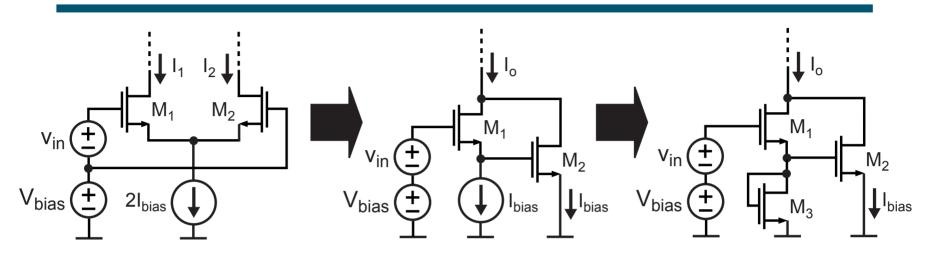
## Creating a Single-Ended Output



Input voltage is again dropped across two transistors

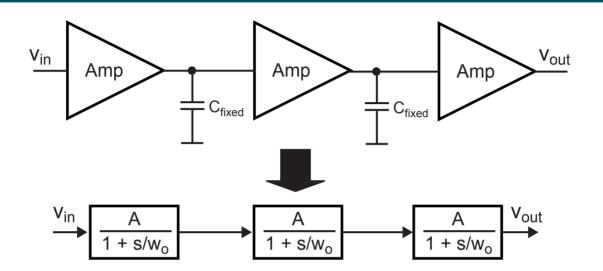
- Ratio given by voltage divider in capacitance
  - Ideally is ½ of input voltage on C<sub>qs</sub> of each device
- Input voltage source sees the series combination of the capacitances of each device
  - Ideally sees ½ of the C<sub>gs</sub> of M<sub>1</sub>
- Currents of each device add to ideally yield ratio:  $\frac{2g_m}{C}$

## Creating the Bias for M<sub>2</sub>



- Use current mirror for bias
  - Inspired by bipolar circuits (see Tom Lee's book, page 198)
- Need to set V<sub>bias</sub> such that current through M<sub>1</sub> has the desired current of I<sub>bias</sub>
  - The current through M<sub>2</sub> will ideally match that of M<sub>1</sub>
- Problem: achievable bias voltage across M<sub>1</sub> (and M<sub>2</sub>) is severely reduced (thereby reducing effective f<sub>t</sub> of device)
  - Do f<sub>t</sub> doublers have an advantage in CMOS?

### Increasing Gain-Bandwidth Product Through Cascading



We can significantly increase the gain of an amplifier by cascading n stages

$$\Rightarrow \frac{v_{out}}{v_{in}} = \left(\frac{A}{1+s/w_o}\right)^n = A^n \frac{1}{(1+s/w_o)^n}$$

Issue – bandwidth degrades, but by how much?

## Analytical Derivation of Overall Bandwidth

The overall 3-db bandwidth of the amplifier is where

$$\left|\frac{v_{out}}{v_{in}}\right| = \left|\frac{A}{1+jw_1/w_o}\right|^n = \frac{A^n}{\sqrt{2}}$$

- w<sub>1</sub> is the overall bandwidth
- A and w<sub>o</sub> are the gain and bandwidth of each section

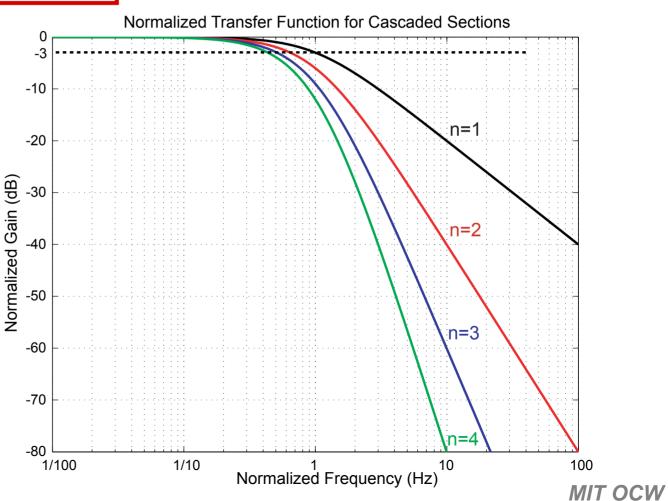
$$\Rightarrow \left(\frac{A}{\sqrt{1 + (w_1/w_o)^2}}\right)^n = \frac{A^n}{\sqrt{2}}$$
$$\Rightarrow \left(1 + (w_1/w_o)^2\right)^n = 2$$
$$\Rightarrow w_1 = w_0 \sqrt{2^{1/n} - 1}$$

- Bandwidth decreases much slower than gain increases!
  - Overall gain bandwidth product of amp can be increased!

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#### **Transfer Function for Cascaded Sections**

$$H(f) = \left|\frac{1}{1+j2\pi f}\right|^n$$



#### **Choosing the Optimal Number of Stages**

To first order, there is a constant gain-bandwidth product for each stage

$$\Rightarrow Aw_o = w_t \Rightarrow w_o = w_t/A$$

- Increasing the bandwidth of each stage requires that we lower its gain
- Can make up for lost gain by cascading more stages
- We found that the overall bandwidth is calculated as

$$w_1 = w_o \sqrt{2^{1/n} - 1} = \frac{w_t}{A} \sqrt{2^{1/n} - 1}$$

Assume that we want to achieve gain G with n stages

$$\Rightarrow A = G^{1/n} \Rightarrow w_1 = \frac{w_t}{G^{1/n}} \sqrt{2^{1/n} - 1}$$

- From this, Tom Lee finds optimum gain  $\approx$  1.65
  - See Tom Lee's book, pp 207-211

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## Achievable Bandwidth Versus G and n

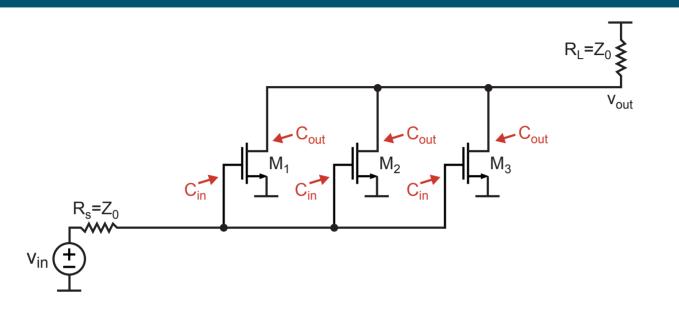
 $w_t$  $2^{1/n}$ Achievable Bandwidth (Normalized to ft) Versus Gain (G) and Number of Stages (n) 0.3  $2^{1/n}$  $w_t$  $w_1$ 0.25  $\overline{G^{1/n}}$ G=10 0.2 G=100  $W_1/W_t$ 0.15 G=1000 A=1.65 0.1 A=3 0.05 0 0 5 10 15 20 25 30 n M.H. Perrott

- Optimum gain per stage is about 1.65
  - Note than gain per stage derived from plot as

 $A = G^{1/n}$ 

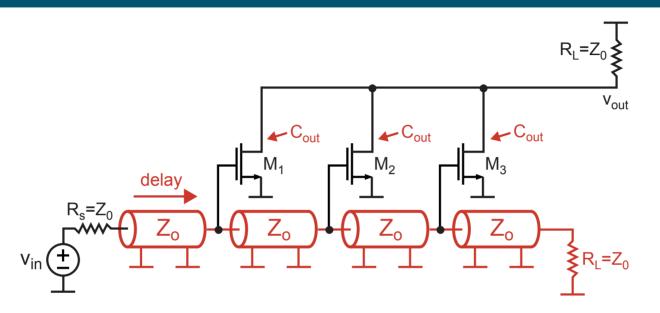
- Maximum is fairly soft, though
- Can dramatically lower power (and improve noise) by using larger gain per stage

## Motivation for Distributed Amplifiers



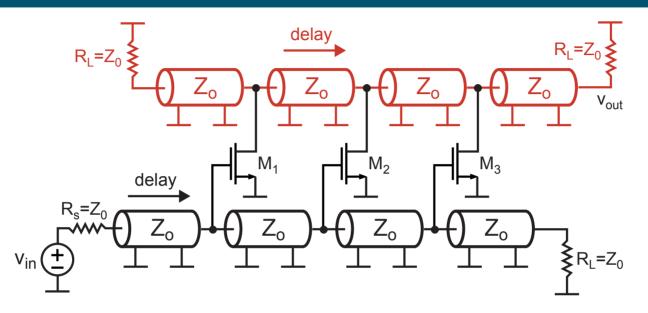
- We achieve higher gain for a given load resistance by increasing the device size (i.e., increase g<sub>m</sub>)
  - Increased capacitance lowers bandwidth
    - We therefore get a relatively constant gain-bandwidth product
- We know that transmission lines have (ideally) infinite bandwidth, but can be modeled as LC networks
  - Can we lump device capacitances into transmission line?

## **Distributing the Input Capacitance**



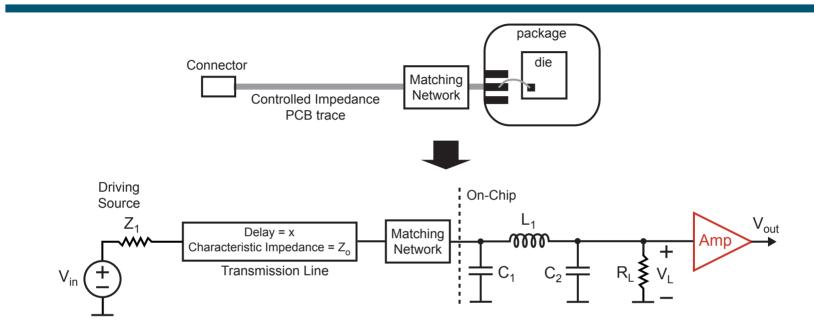
- Lump input capacitance into LC network corresponding to a transmission line
  - Signal ideally sees a real impedance rather than an RC lowpass
  - Often implemented as lumped networks such as T-coils
  - We can now trade delay (rather than bandwidth) for gain
- Issue: outputs are delayed from each other

## **Distributing the Output Capacitance**



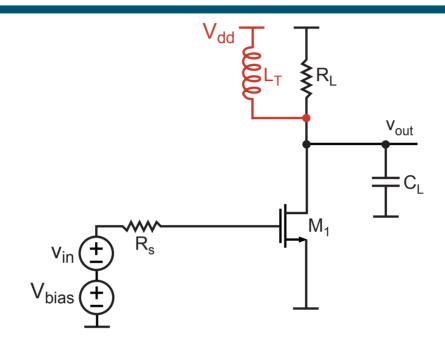
- Delay the outputs same amount as the inputs
  - Now the signals match up
  - We have also distributed the output capacitance!
- Benefit high bandwidth
- Negatives high power, poorer noise performance, expensive in terms of chip area
  - Each transistor gain is adding rather than multiplying!

## **Narrowband Amplifiers**



- For wireless systems, we are interested in conditioning and amplifying the signal over a narrow frequency range centered at a high frequency
  - Allows us to apply narrowband transformers to create matching networks
- Can we take advantage of this fact when designing the amplifier?

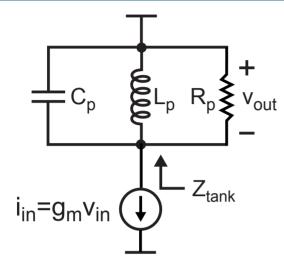
## **Tuned Amplifiers**



- Put inductor in parallel across R<sub>L</sub> to create bandpass filter
  - It will turn out that the gain-bandwidth product is roughly conserved regardless of the center frequency!
    - Assumes that center frequency (in Hz) << f<sub>t</sub>
- To see this and other design issues, we must look closer at the parallel resonant circuit

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### **Tuned Amp Transfer Function About Resonance**



Amplifier transfer function

$$\frac{v_{out}}{v_{in}} = g_m Z_{tank}(s) = \frac{g_m}{Y_{tank}(s)}$$

Note that conductances add in parallel

$$Y_{tank}(s) = \frac{1}{R_p} + \frac{1}{sL_p} + sC_p$$

Evaluate at s = jw

$$Y_{tank}(w) = \frac{1}{R_p} - \frac{j}{wL_p} + jwC_p = \frac{1}{R_p} + \frac{j}{wL_p} \left( -1 + w^2 L_p C_p \right)$$

• Look at frequencies about resonance:  $w = w_o + \Delta w$ 

$$\Rightarrow Y_{tank}(\Delta w) = \frac{1}{R_p} + \frac{j}{(w_o + \Delta w)L_p} \left( -1 + (w_o + \Delta w)^2 L_p C_p \right)$$
$$\approx \frac{1}{R_p} + \frac{j}{w_o L_p} \left( -1 + w_o^2 L_p C_p + 2w_o \Delta w L_p C_p \right)$$
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### **Tuned Amp Transfer Function About Resonance (Cont.)**

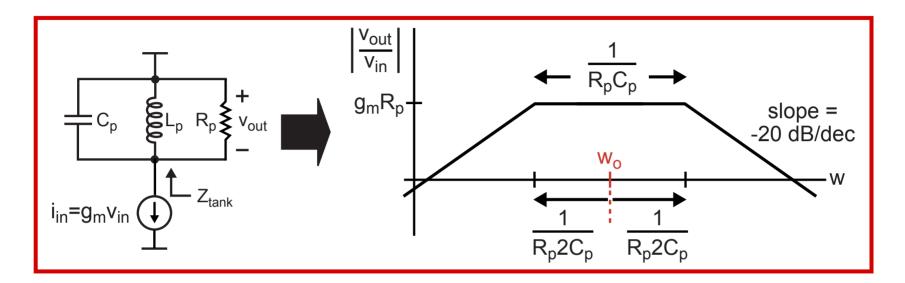
From previous slide

M<sub>-</sub>H<sub>-</sub>

$$Y_{tank}(\Delta w) \approx \frac{1}{R_p} + \frac{j}{w_o L_p} \left( -\frac{1 + w_o^2 L_p C_p}{=0} + 2w_o \Delta w L_p C_p \right)$$
$$\approx \frac{1}{R_p} + \frac{j}{w_o L_p} \left( 2w_o \Delta w L_p C_p \right) = \frac{1}{R_p} + j \Delta w 2C_p$$

• Simplifies to RC circuit for bandwidth calculation!  $Z_{tank}(\Delta w) \approx R_p || \frac{1}{j\Delta w 2C_p}$ 

### **Gain-Bandwidth Product for Tuned Amplifiers**

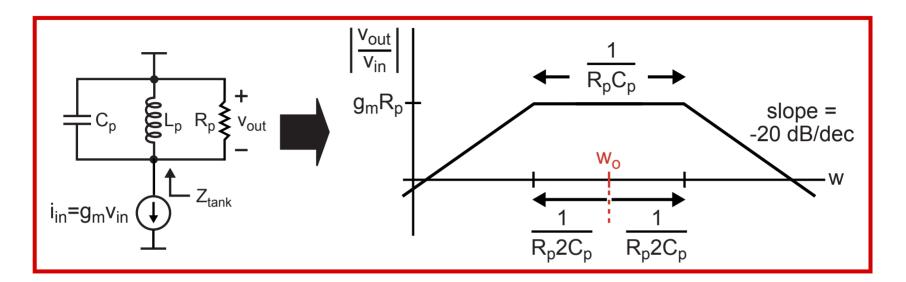


The gain-bandwidth product:

$$G \cdot BW = g_m R_p \frac{1}{R_p C_p} = \frac{g_m}{C_p}$$

- The above expression is independent of center frequency!
  - In practice, we need to operate at a frequency less than the f<sub>t</sub> of the device

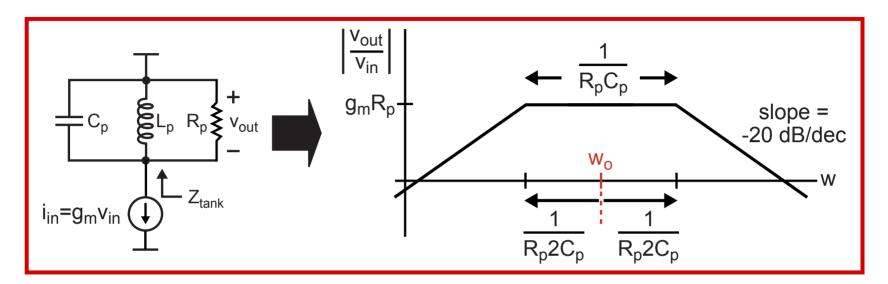
### The Issue of **Q**



- By definition  $Q = w \frac{\text{energy stored}}{\text{average power dissipated}}$
- For parallel tank (see Tom Lee's book, pp 88-89)

at resonance: 
$$Q = \frac{R_p}{w_o L_p} = w_o R_p C_p$$
  
**Comparing to above:**  $Q = w_o R_p C_p = \frac{w_o}{1/(R_p C_p)} = \boxed{\frac{w_o}{BW}}$   
*tt*

## **Design of Tuned Amplifiers**



- Three key parameters
  - **Gain** =  $g_m R_p$
  - Center frequency = w<sub>o</sub>
  - $Q = w_o/BW$
- Impact of high Q
  - Benefit: allows achievement of high gain with low power
  - Problem: makes circuit sensitive to process/temp variations

## *Issue:* C<sub>gd</sub> Can Cause Undesired Oscillation

$$Z_{in}(w) = \frac{1}{jwC_{gs}} || \frac{1}{jwC_{gd}(1 - A_v)}$$
where  $A_v = -g_m Z_{tank}(w)$ 

$$V_{in} \bigoplus_{R_s} C_{gs} \prod_{r_s} M_1$$

At frequencies below resonance, tank looks inductive

$$A_{v} \approx -g_{m}(jwL) \Rightarrow Z_{in}(w) \approx \frac{1}{jwC_{gs}} || \frac{1}{jwC_{gd}(1+g_{m}(jwL))}$$

$$\Rightarrow Z_{in}(w) \approx \frac{1}{jwC_{gs}} || \frac{1}{jwC_{gd} - w^{2}g_{m}C_{gd}L}$$

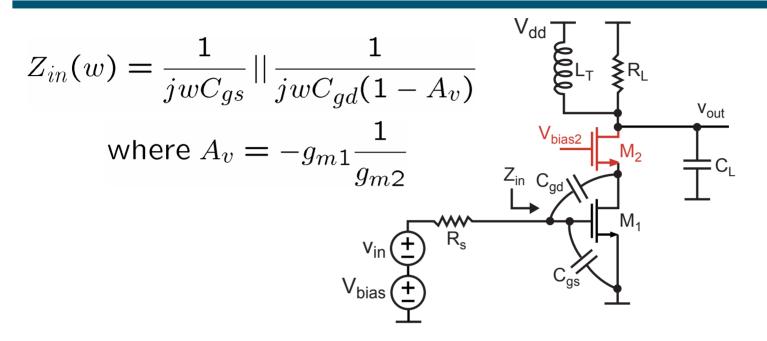
$$\Rightarrow Z_{in}(w) \approx \frac{1}{jwC_{gs}} || \frac{1}{jwC_{gd}} || \frac{-1}{w^{2}g_{m}C_{gd}L}$$

$$Negative$$

$$Resistance!$$

$$M.H. remote$$

## Use Cascode Device to Remove Impact of C<sub>ad</sub>

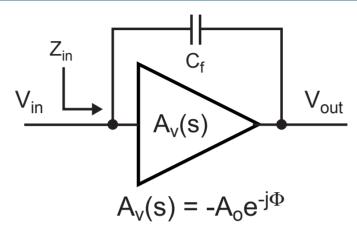


At frequencies above and below resonance

$$Z_{in}(w) = \frac{1}{jwC_{gs}} || \frac{1}{jwC_{gd}(1 + g_{m1}/g_{m2})}$$

Purely Capacitive!

#### Active Real Impedance Generator

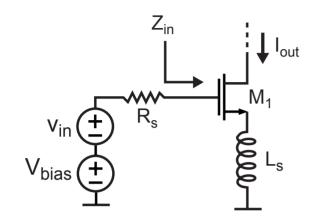


Input impedance:

$$Z_{in}(w) = \frac{1}{jwC_f(1 - A_v)} = \frac{1}{jwC_f(1 + A_o e^{-j\Phi})}$$
$$= \frac{1}{jwC_f(1 + A_o \cos \Phi) + A_o wC \sin \Phi}$$
$$= \frac{1}{jwC_f(1 + A_o \cos \Phi)} || \frac{1}{A_o wC \sin \Phi}$$
**Resistive component!**

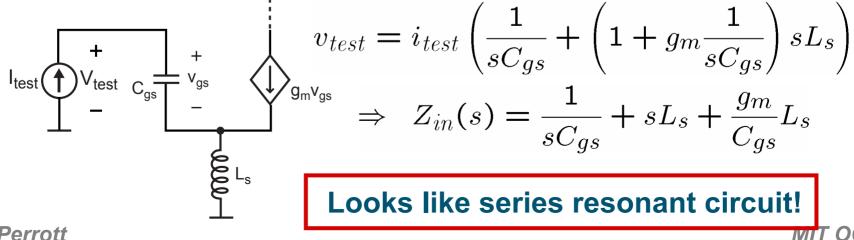
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## This Principle Can Be Applied To Impedance Matching

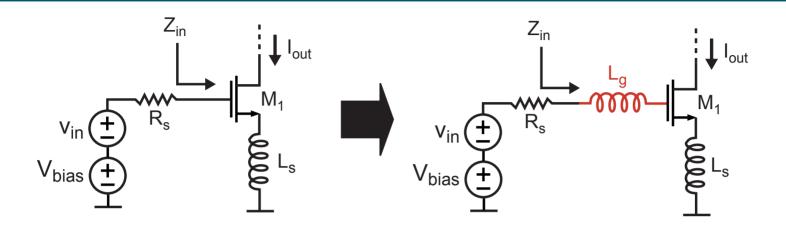


We will see that it's advantageous to make Z<sub>in</sub> real without using resistors

For the above circuit (ignoring C<sub>qd</sub>)



#### **Use A Series Inductor to Tune Resonant Frequency**



Calculate input impedance with added inductor

$$Z_{in}(s) = \frac{1}{sC_{gs}} + s(L_s + L_g) + \frac{g_m}{C_{gs}}L_s$$

Often want purely resistive component at frequency w<sub>o</sub>

Choose L<sub>q</sub> such that resonant frequency = w<sub>o</sub>

i.e., want 
$$\frac{1}{\sqrt{(L_s + L_g)C_{gs}}} = w_o$$